

High-Efficiency High-Density GaN-Based 6.6kW Bidirectional On-board Charger for PEVs - 2017 Annual Merit Review Meeting

EDT067

Dr. Charles Zhu, Principal Investigator
Delta Products Corporation, Livonia, MI
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Contents

Project Overview Project Objective **Project Milestones** Technical Accomplishments and Progress ☐GaN device delivery and test □6.6kw GaN-based B-Sample design, build and test □CPES Alternative design, build and test ☐ Market Introduction Plan ☐ Responses to Previous Year Reviewer's Questions □ Partners ☐ Proposed Future Works □ Summary



Project Overview

Timeline

- Period 2 Start FY16
- Period 2 Finish FY16
- Project Finish FY17
- 71% complete

Budget

- Total project funding DOE share \$1,487,594
- Total Period 2 funding DOE share -\$565,970
- Funding received in Period 2 (FY16): \$454,947

Barriers

- Parasitic parameters in GaN device and PCB restricts the switching frequency
- Topology and control Scheme for bidirectional power flow
- Thermal design to remove heat
- High frequency magnetics
- GaN device cost

Partners

- Transphorm
- CPES at Virginia Tech
- Fiat Chrysler Automobiles





Project Objective

The objective of this project is to design, develop, and demonstrate a 6.6kw isolated bidirectional On-Board Charger (OBC) using Gallium Nitride (GaN) power switches in a vehicle capable of achieving the specifications identified in Table 1, below. The developed OBC will reduce size and weight when compared to commercially existing Silicon (Si) based OBC products in automobiles by 30%-50%.

Parameter	Requirement
Switching Frequency	0.3 - 1 Mega-Hertz (MHz)
Power Efficiency	95%
Power Rating	3.3 kilo-Watt (kW) at 120 Volts Alternating Current (VAC), 6.6kW at 240 VAC (Auto sensing depending on AC input voltage)
Plug-In VAC	120/240 VAC
High Voltage (HV) Battery Voltage Range	250 - 450 Voltage Direct Current (VDC)
Nominal Battery Voltage	350 VDC
AC Line Frequency	50 - 60 Hz
Maximum Coolant Temperature	70°Celcius (C)
Ambient Temp Range	-40 to 70°C
Controller Area Network (CAN) Communication	Yes



FY2016 Objective and Milestones

FY 2016 Objective: Technology Development and market Plan Development

- Design, build and test Iteration III GaN device
- Iteration III GaN device switching performance evaluation
- Advanced circuit development for GaN device application
- Build and test the A-Sample charger
- Design, build and test the B-Sample charger
- Develop and finalize market introduction plan

#	Milestone	Туре	Due Month
MS 2.1	Build the A-Sample charger	Technical	Feb. 2016
MS 2.2	Test the A-Sample charger and report	Technical	May 2016
MS 2.3	Design the B-Sample charger	Technical	June 2016
MS 2.4	Test the B-Sample charger and report	Technical	Dec 2016
DP 2	Completion of the B-Sample charger prototype build	Go/No Go	Nov 2016
MS 3.1	Develop in-vehicle test plan	Technical	Feb. 2017
MS 3.2	Vehicle Integration	Technical	Aug 2017
MS 3.3	Conduct In-vehicle test and report	Technical	Nov 2017
MS 3.4	Completion of the in-vehicle testing	Technical	Dec 2017



Budget Period II Review Meeting



February 24, 2017, Delta Products, Livonia, MI



Lab Demo



Chrysler 2017 Pacifica PHEV Minivan





Contents

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- □ Project Milestones
- ☐ Technical Accomplishments and Progress
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 - □6.6kw GaN-based B-Sample design and build
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- Proposed Future Works
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Three Iterations of GaN HEMT devices have been developed and delivered.

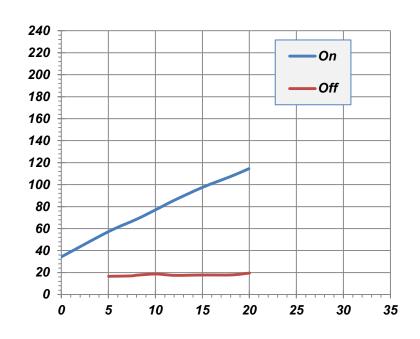
	Iteration I	Iteration II	Iteration III
PN	TPH3205WS	TPH3205WSA	TPH3207WS
Quantities delivered	180	550	190
Rds,on	63mΩ	52mΩ	35mΩ
Co_tr	283pF	247pF	430pF
Qg	10nC	19nC	28nC
Qrr	138nC	136nC	175nC

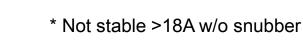
I-3 device has 33% lower Rds, on than I-2 device. Unfortunately, it also has higher charge, which will make switching performance sacrifice. Based on analysis, Delta plan to use I-2 device in A-Sample and B-Sample build.





Switching Losses (uJ) vs. Current (A) of I2 & I3 Devices, (Vds=400V)





I-2 Device, w/o snubber

I-3 Device, w/o snubber*



-Eon

-Eoff

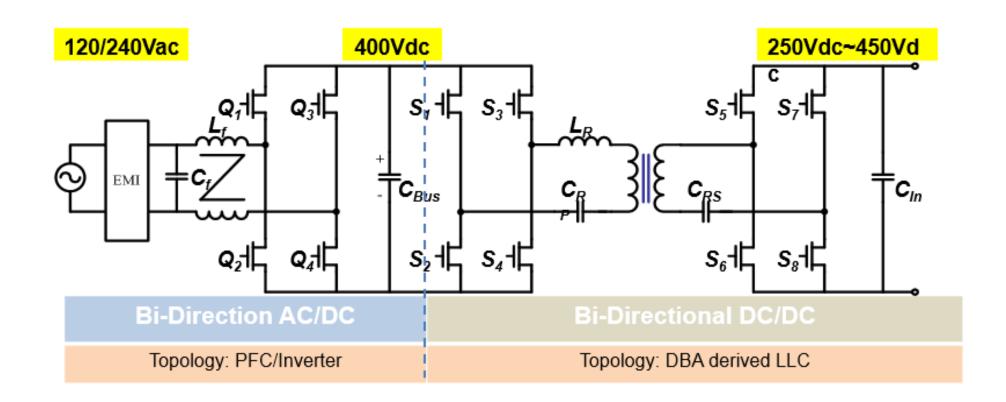


Parameter	Target	B-Sample Result	Production Design Feasibility
Volume	30% -50% reduction 8.1-11.4 liter	58% reduction 6.8 liter	Meet
Switching Frequency	0.3 - 1 Mega-Hertz (MHz)	DC/DC: 0.33~ 0.6MHz DC/AC: 0.3MHz	To optimize for size and efficiency trade-off
Power Efficiency	er Efficiency 95% 95.1%		Meet
Power Rating	3.3kW at 120Vac, 6.6kW at 240Vac	3.3kW at 120Vac, 6.6kW at 240Vac	Meet
AC Voltage Range	120/240 Vac	120/240 Vac	Meet
HVDC Voltage Range	250 - 450 Vdc	250 - 450 Vdc	Meet
Nominal Battery Voltage	350 Vdc	350 Vdc	Meet
AC Line Frequency	50 - 60 Hz	50 - 60Hz	Meet
Maximum Coolant Temperature	70°C	50°C (projected from 30°C test result)	Will meet in production
Ambient Temp Range	-40 to 70°C	To be tested	Will meet in production
(CAN) Communication	Yes	Yes	Meet





Power Stage Topology (half)







B Sample Physical parameters

Dimension: 296x250x92mm

Volume: 6.9 liter

Weight: 12kg

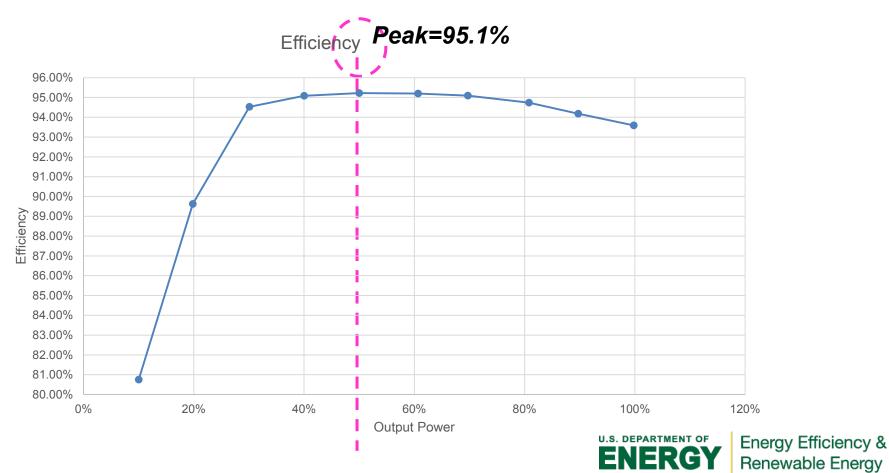
 Water sealed design for under body installation

Liquid Cooling



240Vac Charge Mode Efficiency

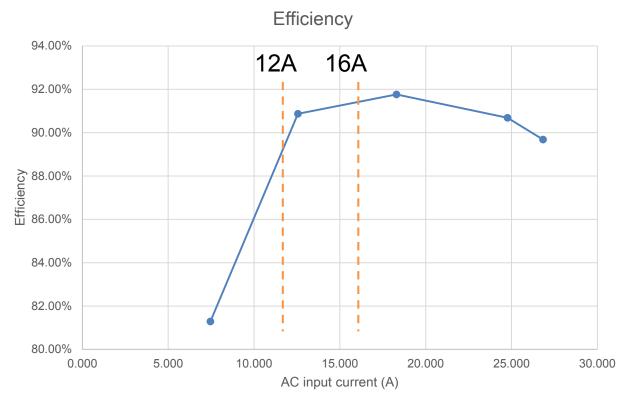
Test Condition: 30 ℃ Water Temp. 240Vac input and 350Vdc output. 100% load is 6.6kw.





120Vac Charge Mode Efficiency

Test Condition: 30 °C Water Temp. 120Vac input and 350Vdc output.

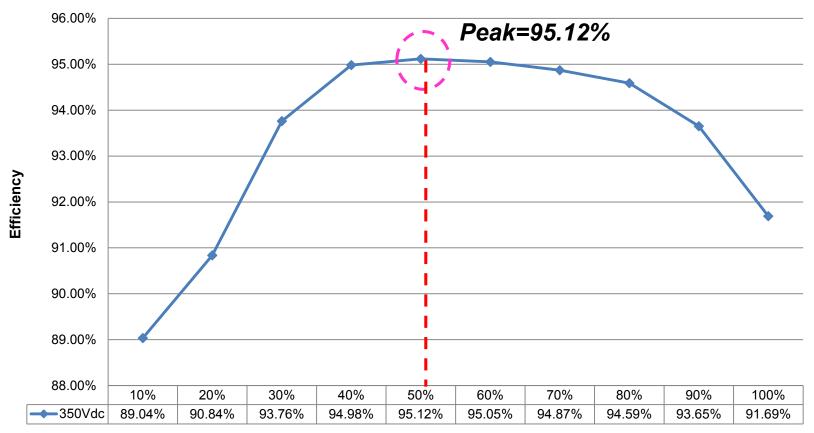






240Vac Discharge Mode Efficiency

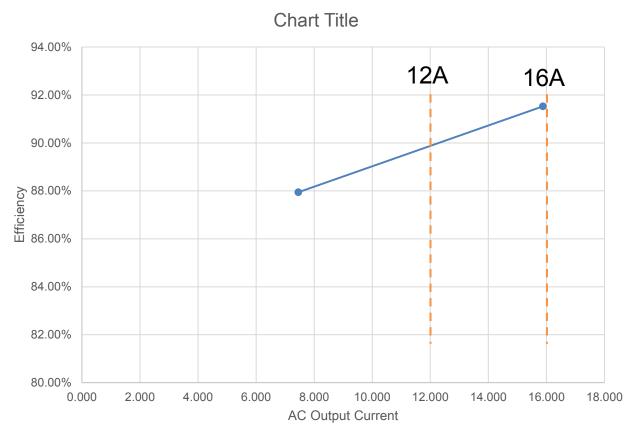
Test Condition: 30 ℃ Water Temp. 350Vdc input and 240Vac output. 100% load is 6.6kw.





120Vac Discharge Mode Efficiency

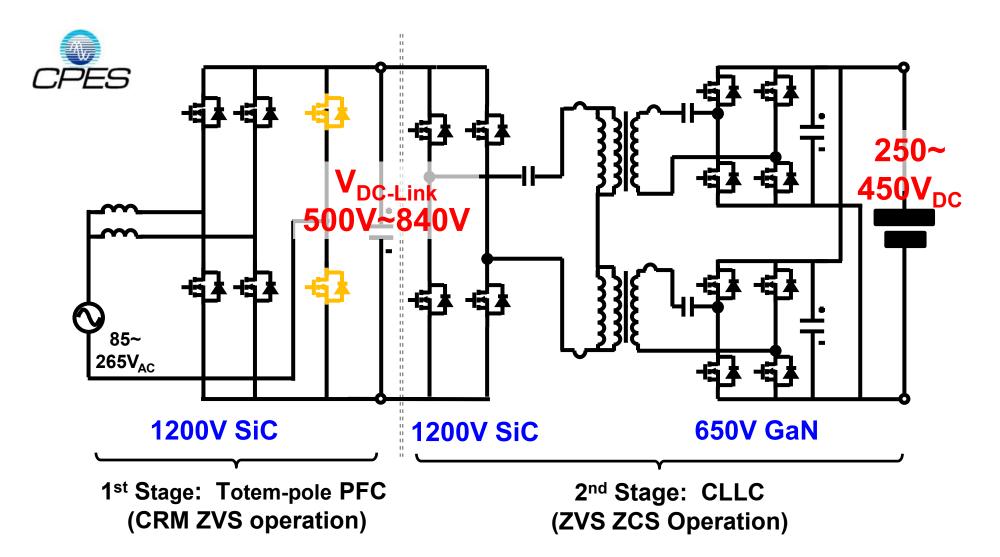
Test Condition: 30 °C Water Temp. 350Vdc input and 120Vac output.







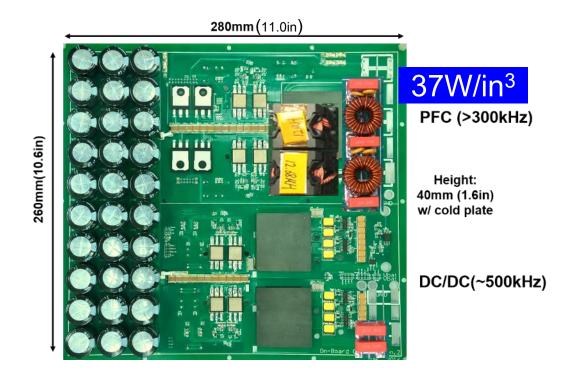
CPES Design: Variable DC-Link





Hardware Prototype (PFC + DCX)



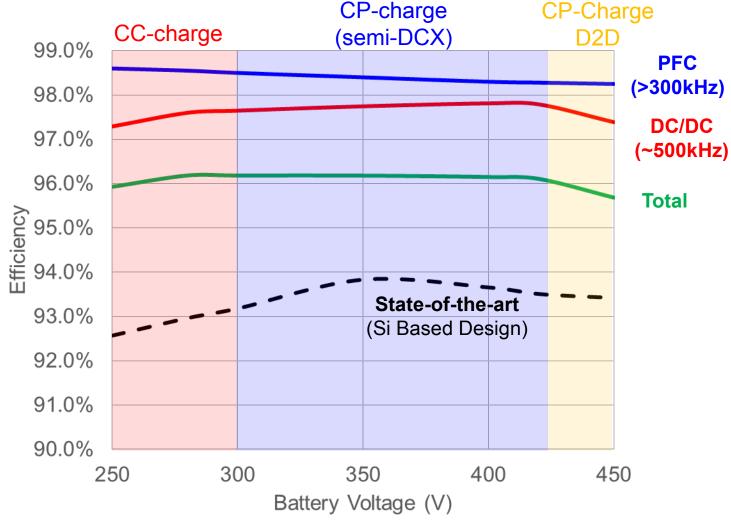






Charging Mode Efficiency (Testing Results)

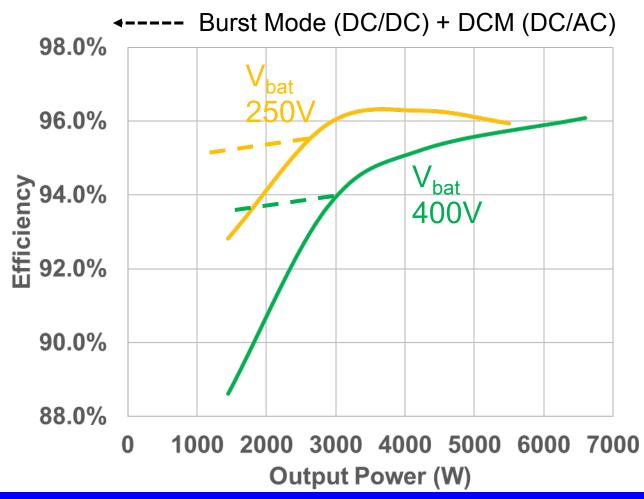






Discharging Mode Total Efficiency (Testing Results)





Further improve efficiency using DCM (AC/DC) and burst mode (DC/DC)



CPES Work Summary



- □ A novel two stage system architecture and control are proposed
 □ 300kHz switching frequency for AC/DC and 500kHz for DC/DC
- ZVS is achieved for all high frequency devices
- □ PCB winding transformer with leakage integration
- □ 96.2% total system efficiency and 37W/in³ Power density

Future Work

- ☐ Light load efficiency improvement with Burst Mode
- ☐ Implement protection function
- ☐ Implement PCB winding coupled inductor

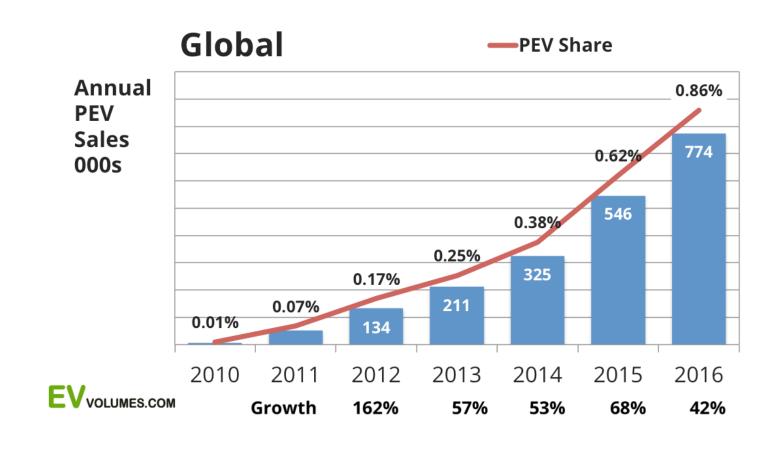


Contents

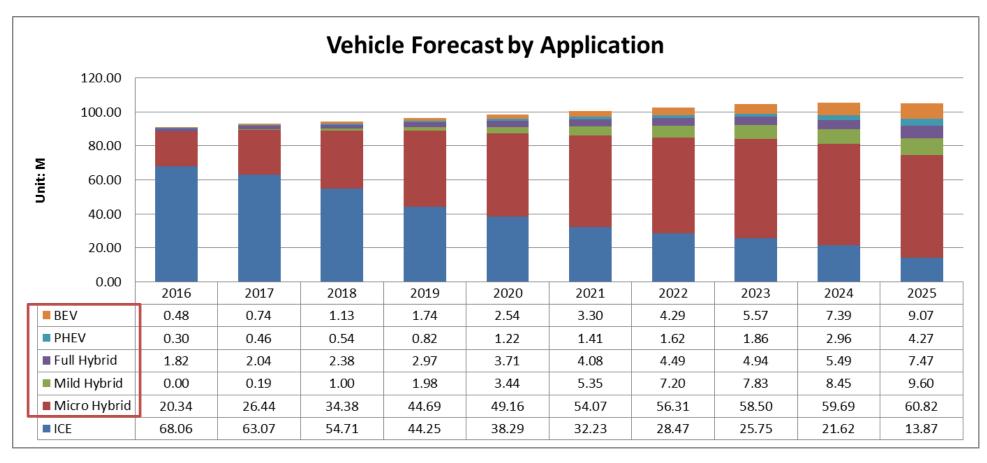
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- Project Milestones
- ☐ Technical Accomplishments and Progress
 - □GaN device delivery and test
 - □6.6kw GaN-based B-Sample design and build
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Global PEV Sales



Global Automotive Market Forecast

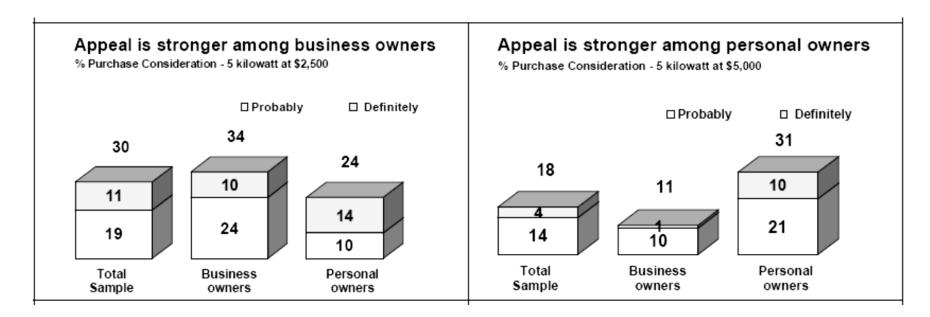


Source: Yole Développement(2015), IEA(2016), Frost & Sullivan(Mar. 2016), IHS (2016), Delta estimation

- 88M to 104M vehicle sales globally in next 10 years
- xEV will grow dramatically

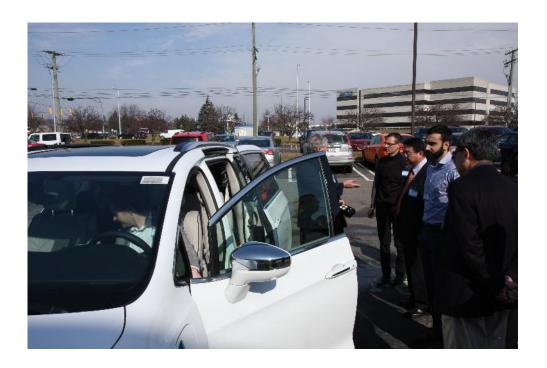


AC Power Option Market Survey by FCA



34% of business owners and 24% of personal owners say they would definitely or probably choose an AC power option if offered.





- Test Vehicle: 2017 Chrysler Pacifica plug-in hybrid minivan
- Drop in replacement of RU OBCM
- Will discuss with FCA for the new feature introduction, target 2020

Commercial Plan

Jan 3, 2017 | FLAT ROCK, Mich.

Mark Fields, Ford president and CEO Announcement:

■A hybrid version of the best-selling F-150 pickup available by 2020 and sold in North America and the Middle East. The F-150 Hybrid, built at Ford's Dearborn Truck Plant, will offer powerful towing and payload capacity and operate as a mobile generator



Partners/Collaborators



Delta Products Corporation (Primary Recipients)

Administrative responsible to DOE, single point of contact Technical direction and program management Timing and deliverables, budget control OBCM Prototypes development and testing, system integration Commercialization



Transphorm, Inc.

High frequency GaN device development GaN device characterization and qualification



CPES at Virginia Tech

GaN device in circuit evaluation
High frequency circuit topology selection and evaluation
High-frequency magnetic components development



FCA US LLC

Vehicle integration and testing Commercialization





DOE Mission Support

Design, build and test two generations of GaN-based OBC.

Approaches

- Reduce switching devices from 76 Si devices to 24 GaN devices
- Increase switching frequency to reduce passive components size
- Develop software switching technology to reduce switching loss

Technical Accomplishment

- Developed and evaluated three iterations of GaN devices.
- Designed, built and tested A-Sample 6.6kw GaN-based OBC to verify thermal performance and packaging design
- Designed, built and tested B-Sample 6.6kw GaN-based OBC to optimize the design with CAN control interface
- Design, build and tested alternative OBC concept Sample with SiC/GaN devices



Proposed Future Work

- FY2017
 - Develop vehicle test plan.
 - Vehicle integration.
 - Test the OBC in vehicle and report

Smarter. Greener. Together.

